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SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR
(AUTONOMOUS)

B.Tech I Year I Semester Regular Examinations January 2020

SEMICONDUCTOR PHYSICS

(CSE and CSIT)

Time: 3 hours

Max. Marks: 60

(Answer all Five Units 5 x 12 = 60 Marks)

UNIT-I

- 1 a Describe the electrical conductivity in a metal using quantum free electronic theory. **8M**
b Write advantages of quantum free electron theory over classical free electron theory. **4M**
- OR**
- 2 a What is effective mass of an electron? Obtain the expression for effective mass of electron in periodic potential. **8M**
b Find relaxation time of conduction electron in metal if its resistivity is $1.54 \times 10^{-8} \Omega\text{-m}$ and it has 5.8×10^{28} conduction electron/ m^3 . Given that $m = 9.1 \times 10^{-31}$ kg, $e = 1.6 \times 10^{-19}$ C. **4M**

UNIT-II

- 3 a Explain the formation of p-n junction diode. **6M**
b Elaborate the variations in width of depletion layer under forward and reverse biased conditions. **6M**
- OR**
- 4 a Discuss the construction and working mechanism of LED. **8M**
b Determine the wavelength of LED fabricated by the CdS material with band gap of 2.45eV. **4M**

UNIT-III

- 5 a Outline the behavior of particle in a one-dimensional infinite potential well in terms of eigen values and eigen function. **8M**
b An electron is confined to a one-dimensional potential box of 2 Å width then, calculate the energies corresponding to the second and forth quantum states (in eV). **4M**
- OR**
- 6 a Write Maxwell's equations for electromagnetic waves in differential and integral form. **6M**
b Explain the propagation of electromagnetic wave in non-conducting media. **6M**

UNIT-IV

- 7 a Derive the relation between the various Einstein's coefficients of absorption and emission of radiation. **8M**
b Explain the condition for population inversion. **4M**
- OR**
- 8 a Differentiate step index and graded index fibers. **6M**
b Give the applications of an optical fiber in various fields. **6M**

UNIT-V

- 9 a Explain the Sol-Gel technique for synthesis of nanomaterial. **6M**
b Write the advantages of sol-gel process. **6M**
- OR**
- 10 a What are carbon nanotubes? Mention its structures. **6M**
b Describe the applications of Carbon nanotubes. **6M**

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